#### Fields and Waves I

Lecture 13
Electric Boundary Conditions

Capacitance

Laplace and Poisson's Equations

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# These slides were prepared through the work of the following people:

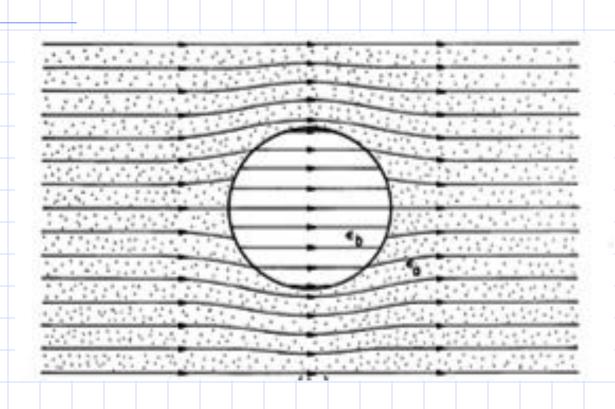
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Materials from other sources are referenced where they are used.

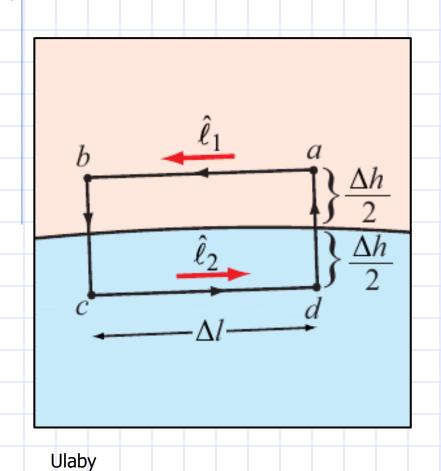
Those listed as Ulaby are figures from Ulaby's textbook.

#### Exam 1

Rework exams will be offered this week on the following skills:
 Skill 1c (phasors)
 Skill 1f (input impedance)
 Skill 1b (wave properties)
 Skill 2a (Smith chart)



Look at this picture again. How do electric fields behave at the boundary between two different dielectrics?



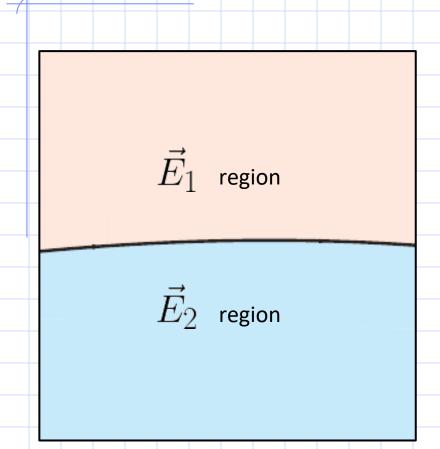
We know that

$$\oint \vec{E} \cdot \vec{dl} = 0$$

- This will hold for any loop we choose, so we can choose Δh → 0 so that the contribution of segments **bc** and **da** goes to zero.
- Note that we have chosen  $\ell_1$  and  $\ell_2$  tangent to the

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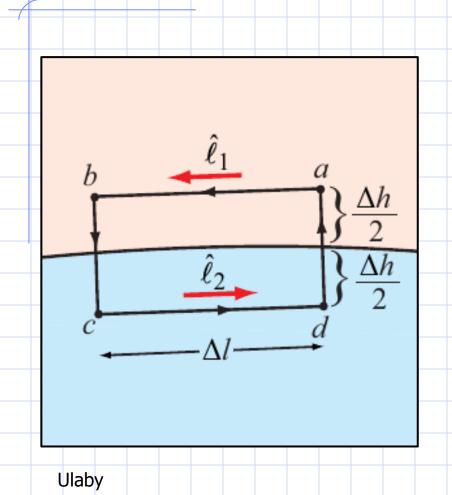
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Therefore we can write

$$\vec{E}_1 = \vec{E}_{1t} + \vec{E}_{1n}$$

$$\vec{E}_2 = \vec{E}_{2t} + \vec{E}_{2n}$$



• We chose  $\ell_1$  and  $\ell_2$  such that

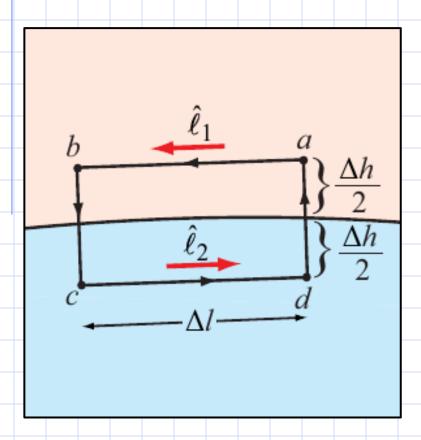
$$\vec{E}_1 \cdot \hat{l}_1 = \vec{E}_{1t}$$

$$\vec{E}_2 \cdot \hat{l}_2 = \vec{E}_{2t}$$

Now we simplify:

$$(\vec{E}_1 - \vec{E}_2) \cdot \hat{l}_1 = 0$$

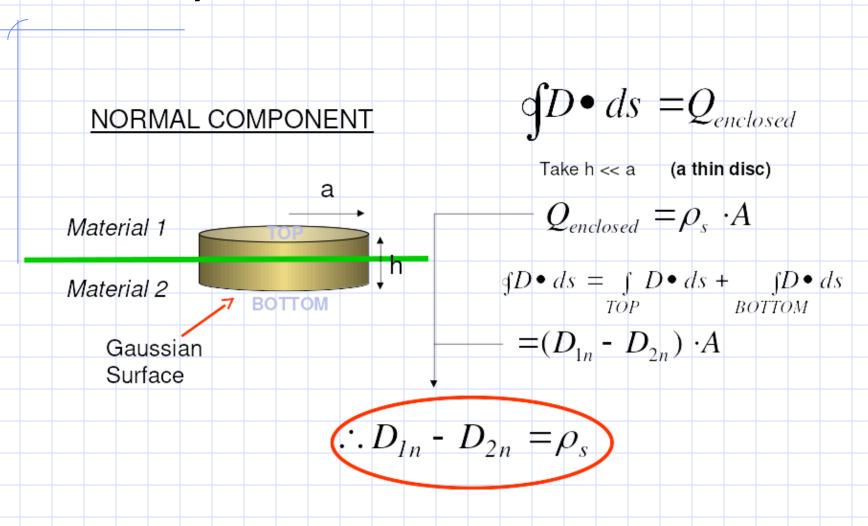
$$\vec{E}_{1t} = \vec{E}_{2t}$$



$$\vec{E}_{1t} = \vec{E}_{2t}$$

- So component of the Efield that is tangent to a media boundary is continuous across it.
- What about normal to the boundary?

Ulaby



Case 1: REGION 2 is a CONDUCTOR, 
$$D_2 = E_2$$

$$\therefore D_{1n} = \rho_s$$

Material 1

 $\rho_s \neq 0$ 

*Material 2* (conductor)

Case 2: REGIONS 1 & 2 are DIELECTRICS with  $\rho_s = 0$ 

Can only really get ρ<sub>s</sub> with conductors

$$D_{1n} = D_{2n}$$

$$\therefore \varepsilon_1 E_{1n} = \varepsilon_2 E_{2n}$$

*Material 1* (dielectric)

Material 2 (dielectric)

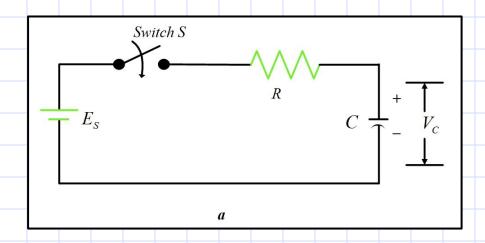
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Do Lecture 13 Exercise 1 in groups of up to 4.

 In earlier EE classes you did analysis on circuits containing capacitors, which have a property called capacitance. What is capacitance, exactly?





- Fundamentally, capacitance describes the relationship between change in charge and change in voltage in an electrical system.
- There are two types of capacitance: self-capacitance and mutual capacitance.

- Self-capacitance describes how much charge is required to increase the electric potential of some conductor by
   1V
- In this case there is no parallel plate. We just need a reference point from which to define the voltage of the conductor.

$$C = \frac{q}{V} = \frac{dq/dt}{dV/dt} = \frac{i(t)}{dV/dt}$$

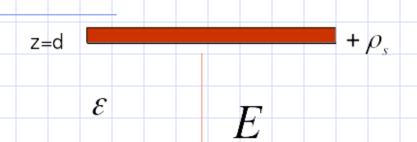
add charge

**0V** 

**1V** 

- Mutual capacitance describes the charge-voltage relationship between two conductors. (This applies to the parallel plate capacitors that you are familiar with.)
- In this case, the charge in the capacitance equation is an equal and opposite charge on *both* plates, and the voltage is *between* them.

$$C = \frac{q}{V} = \frac{dq/dt}{dV/dt} = \frac{i(t)}{dV/dt}$$



Use Gauss' Law,

$$E = -\frac{\rho_s}{\varepsilon} \cdot \hat{a}_{\varepsilon}$$

$$z=0$$
  $-\rho_s$ 

$$V_{top} - V_{bottom} = -\int_{0}^{d} E \cdot dl = \int_{0}^{d} \frac{\rho_{s}}{\varepsilon} \cdot dz$$

$$= \frac{\rho_{s} \cdot d}{\varepsilon}$$

Note: 
$$V \propto 
ho_s$$
 very general result

$$=\frac{\rho_s \cdot d}{\varepsilon}$$

$$\therefore C = \frac{Q}{V} = \frac{\rho_s \cdot A}{d} = \varepsilon \cdot \frac{A}{d}$$
 C of Parallel Plate capacitor

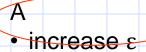
$$C = \varepsilon \cdot \frac{A}{d}$$

Parallel Plate Capacitance

To get large C



increase



decrease

d

This is how electrolytics increase C

$$C = \frac{Q}{V}$$
 charge on 1 conductor  $\Delta V$  between conductors

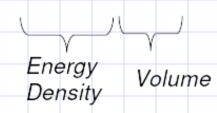
Note that: 
$$\frac{d}{dt}(Q = CV) \Rightarrow I = C\frac{dV}{dt}$$

The energy stored in capacitors is stored in the E-field

Define stored energy: 
$$W_e = \frac{1}{2} \cdot CV^2$$

Substitute values of C and V for parallel plate capacitor

$$W_{e} = \frac{1}{2} \cdot CV^{2} = \frac{1}{2} \cdot \left( \varepsilon \frac{A}{d} \right) \cdot \left( E \cdot d \right)^{2} = \frac{1}{2} \cdot \varepsilon \left| E \right|^{2} \cdot Ad$$



In general we can write the total stored energy as:

$$W_e = \frac{1}{2} \int \epsilon |\vec{E}|^2 dv$$

Or

$$W_e = \frac{1}{2} \int (\vec{D} \cdot \vec{E}) dv$$

Volume integral

Use the Energy Formulation to compute C for the Parallel Plate Capacitor

We know that, 
$$E = -\frac{V_0}{d} \cdot \hat{a}_z$$
 (E in terms of V is needed)

Compute TOTAL ENERGY:

$$W_{e} = \frac{1}{2} \cdot \int \varepsilon \cdot \left(-\frac{V_{0}}{d}\right)^{2} \cdot dv = \frac{1}{2} \cdot \varepsilon \cdot \left(\frac{V_{0}}{d}\right)^{2} \cdot Ad$$

$$= \frac{1}{2} \cdot \left(\frac{A}{d}\right)^{2} \cdot \left(\frac{V_{0}}{d}\right)^{2} \cdot Ad$$

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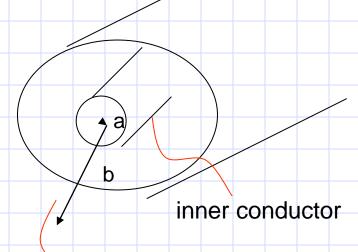
$$= \frac{1}{2} \cdot \left(\frac{A}{d}\right)^{2} \cdot \left(\frac{A}{d}\right)^{2} \cdot C = \varepsilon \cdot \frac{A}{d}$$

Consider a coaxial cable with inner radius, a, and outer radius, b, length /.

The outer conductor was grounded, and inner conductor had voltage  $V = V_0$ .

The relation between surface charge density on the inner conductor and  $V_0$  is  $\rho_{sa} = \varepsilon V_0/(a \ln(b/a))$ .

- Find the capacitance using C = Q/V.
- Find the stored energy in the system by integrating the energy density over the system volume.
- Find the capacitance using the stored energy from part b.



In a previous class, for coaxial cable:

$$V_{ab} = \frac{\rho_{sa} \cdot a}{\varepsilon} \cdot \ln \frac{b}{a}$$

outer conductor

The electric field is given by  $E = V0 / (r \ln(b /a))$  ar.

Surface Charge Density

$$C = \frac{Q}{V} = \frac{2\pi al}{V} \frac{Psa}{V} = \frac{2\pi al}{V_0} \frac{EV_0}{am_a^b} = \frac{2\pi el}{lm^b/a}$$

Note the length in this expression. The practical result is for capacitance per unit length, for which we drop the length.

$$W_{e} = \int \frac{1}{2} E E^{2} dN = \int_{0}^{2} \int_{0}^{2\pi} \int_{0}^{b} \frac{1}{2} E \frac{V_{o}^{2}}{r^{2} (\ln \frac{b}{a})^{2}} r dr dQ dE$$

$$= \frac{1}{2} E \frac{V_{o}^{2}}{(\ln \frac{b}{a})^{2}} \int_{0}^{2\pi} \int_{0}^{b} \frac{dr}{r} dQ dE = \frac{1}{2} E \frac{V_{o}^{2}}{(\ln \frac{b}{a})^{2}} \cdot \ln \frac{b}{a} 2\pi I$$

$$= \frac{\pi E I V_{o}^{2}}{\ln \frac{b}{a}}$$

$$= \frac{1}{2} CV^{2} = \omega_{e} \Rightarrow C = \frac{2\omega_{e}}{V^{2}} = \frac{2}{V_{o}^{2}} \frac{\pi E I V_{o}^{2}}{\ln \frac{b}{a}} = \frac{2\pi E I}{\ln \frac{b}{a}}$$

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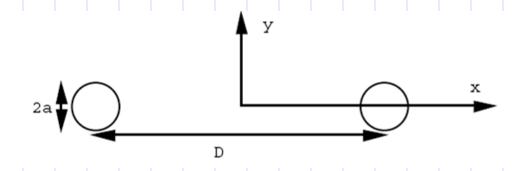
Same Result-

The objective of this problem is to determine the capacitance between 2 conducting wires.

We will assume there are equal magnitude, opposite sign, uniform surface charge densities on the two wires.

What is the voltage difference between the wires?

What is the capacitance?



Electric Field for a Single Wire Located at x=x<sub>o</sub> and y=y<sub>o</sub>

$$E_{R}(R) = \frac{\rho_{s}a}{\varepsilon R}$$

$$R = \sqrt{(x - x_o)^2 + (y - y_o)^2}$$

 This yields an equation for the electric field on the xaxis between the two wires with same charge (the wires are parallel to the z-axis):

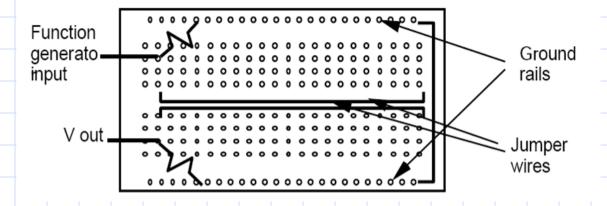
$$\vec{E} = \frac{\rho_s a}{\epsilon} \left( \frac{1}{x + \frac{D}{2}} + \frac{1}{\frac{D}{2} - x} \right) \hat{a}_x$$

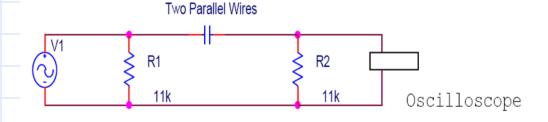
$$|x| < \left( \frac{D}{2} - a \right) \text{ and y=0}$$

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$$V_{LR} = -\int_{0/3-\alpha}^{-185} \frac{\partial}{\partial x} \frac{\partial x}{\partial x} \frac{\partial}{\partial x} \frac{\partial}{\partial x} \frac{\partial}{\partial x} \frac{\partial}{\partial x} \frac{\partial}{\partial x} \frac{\partial}{$$

- Any 2 conductors have capacitance (such as wires on a breadboard)
- Estimate the capacitance of the setup below

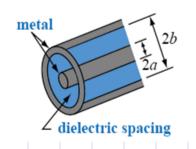


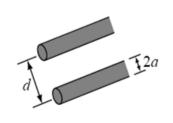


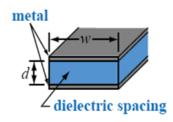
Dimensions for experiment (yours may differ)

$$a = wire radius$$
 $b = wire + insulation radius = a + \Delta$ 
 $c = 0.1a$ 
 $c = 0.1a$ 
 $c = 0.1a$ 
 $c = 0.1a$ 

From Lecture 5







Capacitance per unit length: c F/m

$$\frac{2 \pi \varepsilon}{\ln \frac{b}{a}}$$

$$\frac{\pi \varepsilon}{\ln \left[ \frac{d}{2a} + \sqrt{\left( \frac{d}{2a} \right)^2 - 1} \right]}$$

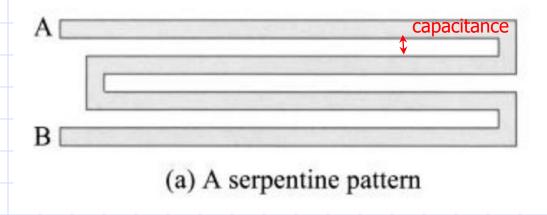
$$\frac{\mathcal{E}W}{d}$$

$$\approx \frac{\pi \varepsilon}{\ln \left[\frac{d}{a}\right]} \quad \text{for } d >> 2$$

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Do Lecture 13, Exercise 2 in groups of up to 4.

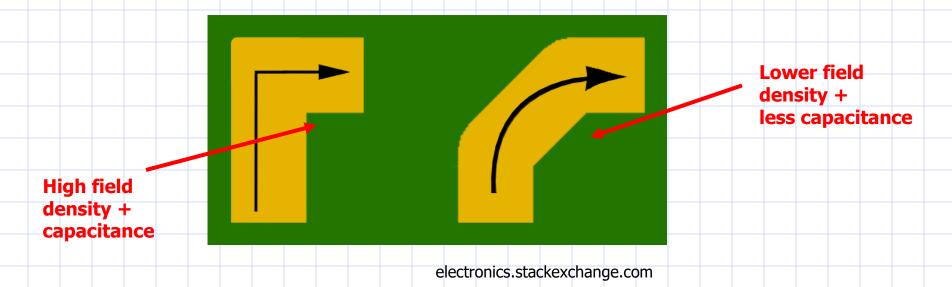
- In Ulaby, capacitance is generally described between two isolated conductors separated by a dielectric. But it also occurs between different parts of a single conductor.
- In circuit design, this unwanted effect is called "parasitic capacitance."
- Circuit designers choose wire geometries to reduce this effect (and other effects)



bjpcjp.github.io

#### From Lecture 5

- In Ulaby, capacitance is generally described between two isolated conductors separated by a dielectric. But it also occurs between different parts of a single conductor.
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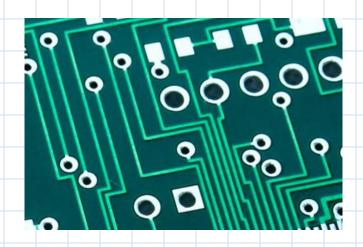


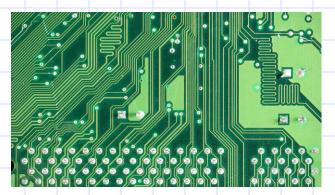
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#### From Lecture 5

- This has inspired changes in circuit design, such as the 45degree angles in the PCB at right.
- This effect can be relevant for precise timing / digital circuit applications but is often overestimated





Hackaday

#### Laplace and Poisson Equations

Integral Form

Differential Form

$$\oint \vec{D} \cdot \vec{ds} = \int \rho \cdot dv$$

$$abla \cdot \vec{D} = 
ho$$

$$\oint \vec{E} \cdot d\vec{l} = 0$$

$$\nabla \times \vec{E} = 0$$

What if we try to rewrite Maxwell's Equations in terms of voltage?

$$ec{E} = -
abla V$$

First, the curl equation

$$\vec{E} = -\nabla V \Rightarrow \nabla \times \vec{E} = 0$$

$$\text{since } \nabla \times (\nabla f) = 0$$

Next, the divergence equation

Laplacian of V = divergence of gradient of V
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Laplace's Equation:

$$\nabla^2 V = 0$$

Poisson's Equation

$$\nabla^2 V = -\frac{\rho}{\varepsilon}$$

$$\nabla^{2} = \begin{bmatrix} \frac{\partial V}{\partial x} & \frac{\partial V}{\partial y} & \frac{\partial V}{\partial z} \end{bmatrix} \bullet \begin{bmatrix} \frac{\partial}{\partial x} \\ \frac{\partial}{\partial y} \\ \frac{\partial}{\partial z} \end{bmatrix} = \frac{\partial^{2}V}{\partial x^{2}} + \frac{\partial^{2}V}{\partial y^{2}} + \frac{\partial^{2}V}{\partial z^{2}}$$
(in cartesian coordinates)

Cylindrical Laplacian Operator:

$$\nabla^{2}V = \frac{1}{r}\frac{\partial}{\partial r}\left(r\frac{\partial V}{\partial r}\right) + \frac{1}{r^{2}}\frac{\partial^{2}V}{\partial \phi^{2}} + \frac{\partial^{2}V}{\partial z^{2}}$$

Spherical Laplacian Operator:

$$\nabla^2 V = \frac{1}{r^2} \frac{\partial}{\partial r} (r^2 \frac{\partial V}{\partial r}) + \frac{1}{r^2 sin\theta} \frac{\partial}{\partial \theta} (sin\theta \frac{\partial V}{\partial \theta}) + \frac{1}{r^2 sin^2 \theta} \frac{\partial^2 V}{\partial \phi^2}$$

- Laplace's Equation and Poisson's Equation are general mathematical expressions that allow us to solve scalar fields if we know the boundary conditions. They are used for solving for:
  - Voltage
  - Heat
  - Gravity
  - Aspects of fluid flow
  - Various abstract mathematical fields
  - etc.

**Boundary Conditions** 

In General

$$D_{n_1} - D_{n_2} = \rho_s \quad E_{t_1} = E_{t_2}$$

Dielectric-Dielectric

$$D_{n1} = D_{n2} \qquad E_{t1} = E_{t}$$

Conductor-Dielectric

$$D_{n1} = \rho_s \qquad E_{t1} = 0$$

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**Boundary Conditions** 

Dielectric-Dielectric

$$D_{n1} = D_{n2} - E_{t1} = E_{t2}$$

Writing in terms of voltage:

$$\varepsilon_{1} \frac{\partial V_{1}}{\partial n} = \varepsilon_{2} \frac{\partial V_{2}}{\partial n} \qquad V_{1} = V_{2}$$

here, n represents direction of boundary normal

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**Boundary Conditions** 

Dielectric-Dielectric

$$D_{n1} = D_{n2} - E_{t1} = E_{t2}$$

Writing in terms of voltage:

$$\varepsilon_{1} \frac{\partial V_{1}}{\partial n} = \varepsilon_{2} \frac{\partial V_{2}}{\partial n} \qquad V_{1} = V_{2}$$

this limit ensures voltage continuity

**Boundary Conditions** 

Conductor-Dielectric

$$D_{n1} = \rho_s$$

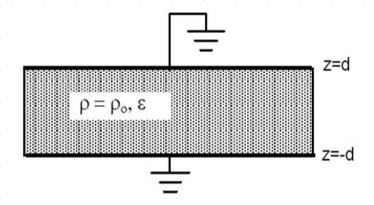
$$E_{t1} = 0$$

$$\frac{\partial V_1}{\partial n} = \rho_s$$

$$V_1 = const$$

- Coulomb's Law is already a solution
- All other voltage expressions can be checked with one of these equations
- This is the most common way of finding electric fields

A charged region of a semiconductor is sandwiched between two grounded conductors as shown below.



Solve for V(z) directly using Poisson's Equation

Find **E** and **D** 

Find the charge density on the conductors

a. 
$$\nabla^2 V = - \int_{\mathcal{E}} \mathcal{E} \Rightarrow \mathcal{R} V = V(\mathcal{E})$$
,  $\nabla^2 V = \frac{d^2 V}{d \mathcal{E}^2}$ 

$$\frac{dV}{d \mathcal{E}} = -\frac{p \mathcal{E}}{\mathcal{E}} + C_1 \Rightarrow \dots = -\frac{p \mathcal{E}^2}{2 \mathcal{E}} + C_1 \mathcal{E} + C_2$$

$$V(d) = 0 = -\frac{p \mathcal{E}^2}{2 \mathcal{E}} + C_1 \mathcal{E} + C_2$$

$$V(-d) = 0 = -\frac{p \mathcal{E}^2}{2 \mathcal{E}} + -C_1 \mathcal{E} + C_2$$

$$V(-d) = 0 = -\frac{p \mathcal{E}^2}{2 \mathcal{E}} + -\frac{p \mathcal{E}^2}{2 \mathcal{E}} + -\frac{p \mathcal{E}^2}{2 \mathcal{E}} + -\frac{p \mathcal{E}^2}{2 \mathcal{E}} + \frac{p \mathcal{E}^2}{2 \mathcal{E}} = \frac{p \mathcal{E}^2}{2 \mathcal{E}} + \frac{p \mathcal{E}^2}{2 \mathcal{E}} + \frac{p \mathcal{E}^2}{2 \mathcal{E}} = \frac{p \mathcal{E}^2}{2 \mathcal{E}} + \frac{p \mathcal{E}^2}{2 \mathcal{E}} + \frac{p \mathcal{E}^2}{2 \mathcal{E}} = \frac{p \mathcal{E}^2}{2 \mathcal{E}} + \frac{p \mathcal{E}^2}{2 \mathcal{E}} + \frac{p \mathcal{E}^2}{2 \mathcal{E}} = \frac{p \mathcal{E}^2}{2 \mathcal{E}} + \frac{p \mathcal{E}^2}{2 \mathcal{E}} + \frac{p \mathcal{E}^2}{2 \mathcal{E}} = \frac{p \mathcal{E}^2}{2 \mathcal{E}} + \frac{p \mathcal{E}^2}{2 \mathcal{E}} + \frac{p \mathcal{E}^2}{2 \mathcal{E}} = \frac{p \mathcal{E}^2}{2 \mathcal{E}} + \frac{p \mathcal{E}^2}{2 \mathcal{E}} = \frac{p \mathcal{E}^2}{2 \mathcal{E}} + \frac{p \mathcal{E}^2}{2 \mathcal{E}} + \frac{p \mathcal{E}^2}{2 \mathcal{E}} = \frac{p \mathcal{E}^2}{2 \mathcal{E}} + \frac{p \mathcal{E}^2}{2 \mathcal{E}} + \frac{p \mathcal{E}^2}{2 \mathcal{E}} = \frac{p \mathcal{E}^2}{2 \mathcal{E}} + \frac{p \mathcal{E}^2}{2 \mathcal{E}}$$

A coaxial cable has an inner conductor (at r = a) held at voltage  $V_0$  and an outer conductor (at r = b) that is grounded. There is no charge other than the surface charge on the conductors.

Solve for V(r) directly using Laplace's Equation

Solve for **E** and **D** 

What is the charge density on the two conductors?

What is the capacitance per unit length?

$$b. \vec{E} = -\nabla V = -\frac{\partial V}{\partial r} \hat{a}_r = -\frac{V_o}{h v_a} \frac{1}{b r} \left( -\frac{b}{r s} \right) \hat{a}_r = \frac{V_o}{r h v_a} \hat{a}_r$$

$$\vec{D} = \varepsilon \vec{E} = \frac{\varepsilon V_o}{r h v_a} \hat{a}_r$$

- ...but as engineers, you all know that integrals can be very difficult to evaluate for all but very simple geometries.
- So how do we solve for V(r) when the geometry is more complex?
- We rely on numerical methods
  - Finite Difference
  - Finite Elements
  - Method of Moments
  - Etc.